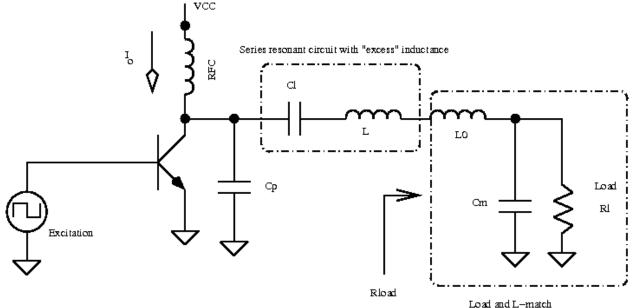
Class-E design process

This design process is based on the assumption of a "perfect" transistor switch and an output network Q-factor greater than about 5-7 (10% or so error) and a perfect inductive choke between the drain and power supply. Output circuit blocks all harmonics allowing only fundamental frequency power to load. This is not completely valid for low Q As output Q factor rises to 10 or more, the assumption of fundamental signal transmission to the load with negligible harmonic content becomes more valid.



Component	Name/Function	Notes
RFC	Bias choke	Impedance at least 10-15 times
		R_{load}
$C_{\rm p}$	Drain shunt capacitance	Combination of intrinsic drain
		source capacitance and
		externally applied capacitance
C_{l}	Series capacitance	Needed to achieve Q-factor
L	Series inductor	Combination of "series
		resonant" LC network
		inductance L _{res} plus excess
		inductance L _{exc} to achieve
		proper fundamental drain
		current/voltage phasing.
		$L=L_{res}+L_{exc}$
L_0	Matching inductor	Part of L-match to 50 ohm
		load. This is absorbed into L.
C _m	Matching capacitor	Part of L-match to 50 ohms
R_1	Load resistor	50 ohms (usually, but not
		necessarily).
R _{load}	Resistive part of load seen by	This is transformed by the L-
	switch at fundamental	match network to R ₁ (50 ohms,
	frequency	etc.)

For the design, we need to specify:

- 1. Output power P_{load}
- 2. The load impedance R_1 (usually 50Ω).
- 3. Supply voltage V_{cc}. (Note: this needs to be based on max transistor breakdown voltage, which should be more than 3.6 times the supply voltage.)
- 4. Operating center frequency $\omega = 2\pi \cdot f$.
- 5. Desired output circuit Q (Determines bandwidth, choose > 5 or so, otherwise component values shift as a result of the simplifying assumptions used in the analysis. Q=10 or more gives very little error).
- Step 1: If switching device shunt capacitance is known, specify the desired output power P_{load} and the DC supply voltage V_{cc} . This yields a relationship between I_0 and the load resistance from

$$P_{load} = \frac{8 \cdot V_{cc}^2}{(\pi^2 + 4) R_{load}} = V_{cc} I_0.$$

 From the expected supply voltage and currents needed to provide the desired power, the drainsource shunt capacitance is yielded by

$$I_0 = \omega \pi \cdot C_P V_{cc}.$$

• Compute the required "excess inductance" Lexc:

$$L_{exc} = \frac{1.153 \cdot R_{load}}{\omega}$$

 Compute the resonant inductance L_{res} and the series capacitance based on chosen Q factor and resonant frequency ω:

$$C_{l} = \frac{1}{Q \cdot R_{load} \cdot \omega}$$

$$L_{res} = \frac{Q \cdot R_{load}}{\omega}.$$

• Compute the L-match parallel capacitance based on the values for R₁ and R_{load}:

$$C_m = \frac{1}{\omega \cdot R_l} \sqrt{\frac{R_l}{R_{load}} - 1}.$$

• Calculate L-match series inductance:

$$L_0 = C_m \cdot R_l \cdot R_{load}$$
.

We now have the full design. Looking at a specific example, let us choose a set of specifications.

- 1. $V_{cc}=12V$
- 2. $P_{load}=5W$
- 3. Q=10
- 4. $\omega = 2\pi \cdot 6.9 \times 10^6 \text{ rad/sec}$

Following the design procedure, we compute

•
$$R_{load} = \frac{8 \cdot V_{cc}^2}{\left(\pi^2 + 4\right)P_l} = \frac{(8)(12)(12)}{(13.869)(5)} = 16.6\Omega$$

•
$$I_0 = \frac{P_{load}}{V_{cc}} = \frac{5}{12} = 0.4167A$$

The needed shunt drain-source capacitance.

•
$$C_P = \frac{I_0}{\omega \cdot \pi \cdot V_{cc}} = \frac{0.4167}{(6.283)(6.9x10^6)(3.1415)(12)} = 255pF$$

The excess inductance needed to have Class-E operation.

•
$$L_{exc} = \frac{1.153 \cdot R_{load}}{\omega} = \frac{(1.153)(16.6)}{(6.283)(6.9x10^6)} = 441nH$$

The resonant part at 6.9MHz with a Q of 10.

•
$$C_l = \frac{1}{(10)(16.67)(6.283)(6.9x10^6)} = 139 pF$$

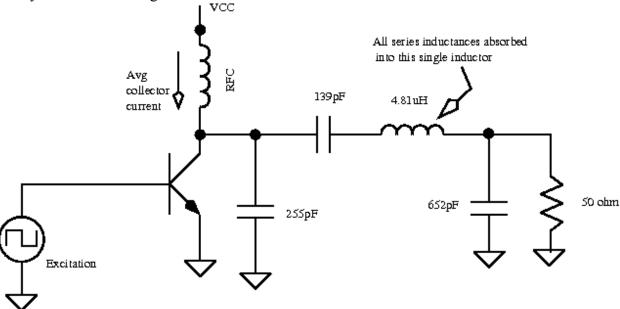
•
$$L_{res} = \frac{Q \cdot R_{load}}{\omega} = \frac{(10)(16.67)}{(6.28)(6.9x10^6)} = 3.829uH$$

L-match to 50 ohm load.

•
$$C_m = \frac{1}{(6.283)(6.9x10^6)(50)} \sqrt{\frac{50}{16.67} - 1} = 652 pF$$

•
$$L_0 = (6.52x10^{-10})(50)(16.67) = 544nH$$

This yields the following circuit.



This circuit yields the drain waveforms that clearly exhibit class e characteristics.

